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Photointerrupter, double-layer mold type RPI-441C1

The RPI-441C1 is a compact, double-layer mold photointerrupter.

While the gap has a width of 4mm, the body has the compact dimensions of $8mm(w) \times 5.2mm(h) \times 4.2mm(d)$.

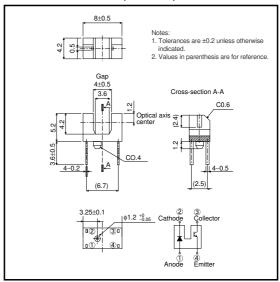
Applications

Optical control equipment Facsimiles Printers

Features

- 1) Compact with a 4mm gap.
- 2) High precision position detection(slit width of 0.5mm).
- 3) Minimal influence from stray light.
- 4) Low collector-emitter voltage.

●External dimensions (Unit : mm)



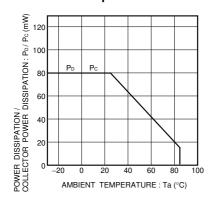
● Absolute maximum ratings (Ta=25°C)

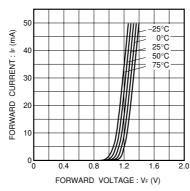
Parameter		Symbol	Limits	Unit
Input(LED)	Forward current	lF	50	mA
	Reverse voltage	V R	5	V
	Power dissipation	Po	80	mW
Output (photo- (transistor)	Collector-emitter voltage	VCEO	30	V
	Emitter-collector voltage	VECO	4.5	V
	Collector current	lc	30	mA
	Collector power dissipation	Pc	80	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		Tstg	-30 to +85	°C

●Electrical and optical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
Input charac- teristics	Forward voltage	VF	-	1.3	1.6	V	I _F =50mA
	Reverse current	IR	-	_	10	μΑ	V _R =5V
Output charac- teristics	Dark current	Iceo	-	_	0.5	μΑ	VcE=10V
	Peak sensitivity wavelength	λР	-	800	_	nm	-
Transfer charac- teristics	Collector current	Ic	0.2	0.55	_	mA	VcE=5V, Ir=20mA
	Collector-emitter saturation voltage	V _{CE(sat)}	-	_	0.4	V	I=20mA, Ic=0.1mA
	Response time	tr · tr	_	10	_	μs	Vcc=5V, I _F =20mA, R _L =100Ω

Electrical and optical characteristic curves





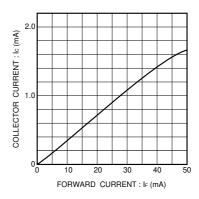


Fig.1 Power dissipation and collector power dissipation vs. ambient temperature

Fig.2 Forward current vs. forward voltage

Fig.3 Collector current vs. forward current

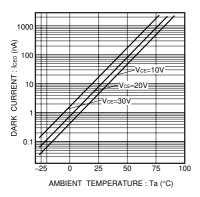


Fig.4 Dark current vs. ambient temperature

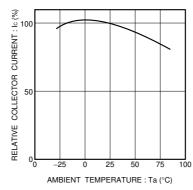


Fig.5 Relative output vs. ambient temperature

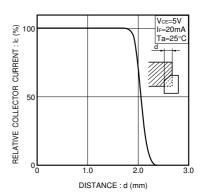
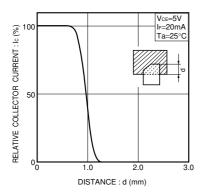


Fig.6 Relative output vs. distance (I)





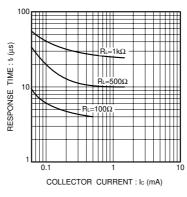


Fig.8 Response time vs. collector current

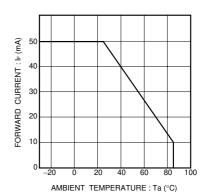


Fig.9 Forward current vs. ambient temperature

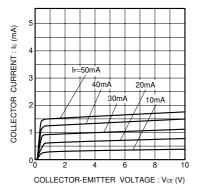
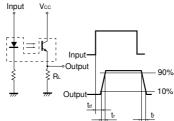


Fig.10 Output characteristics



- t_d: Delay time
- tr: Rise time (time for output current to rise from 10% to 90% of peak current)
- tr: Fall time (time for output current to fall from 90% to 10% of peak current)

Fig.11 Response time measurement circuit

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